# NSN 5961-00-937-4412

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Inclosure Material:

Metal

**Overall Length:** 

0.300 inches

## **Overall Diameter:**

0.875 inches

# Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

## Features Provided:

Hermetically sealed case

Thread Size:

0.312 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

140.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 5.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

#### Power Rating Per Characteristic:

125.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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